

Current Transducer HAIS 50..400-P and HAIS 50..100-TP

For the electronic measurement of currents: DC, AC, pulsed..., with a galvanic isolation between the primary circuit (high power) and the secondary circuit (electronic circuit).



Electrical data



All data are given with a $\mathbf{R}_{1} = 10 \text{ k}\Omega$

Primary nominal Primary current Type **RoHS** since current rms measuring range date code $I_{_{\mathrm{PN}}}(A)$ $I_{_{\mathrm{PM}}}(A)$ 50 ± 150 HAIS 50-P, HAIS 50-TP 1) 45231, 46272 100 ± 300 HAIS 100-P, HAIS 100-TP 1) 45231, 46012 150 ± 450 **HAIS 150-P** 46172 200 ± 600 **HAIS 200-P** 45231 400 ± 600 **HAIS 400-P** 47096 V_{OUT} Output voltage (Analog) @ I $\mathbf{V}_{\text{REF}} \pm (0.625 \cdot \mathbf{I}_{\text{P}}/\mathbf{I}_{\text{PN}}) V$ **I**_P = 0 $\mathbf{V}_{\text{REF}} \pm 0.025$ V V_{RFF} Reference voltage²⁾ - Output voltage 2.5 ± 0.025 V \mathbf{V}_{REF} Output impedance typ. 200 Ω $\boldsymbol{V}_{\text{\tiny REF}}$ Load impedance ≥ 200 kΩ R Load resistance ≥ 2 kΩ **R**_{out} < 10 Output internal resistance Ω \mathbf{C}_{L} Capacitive loading < 1 μF V_c Supply voltage (± 5 %) 5 V Current consumption @ V_{c} = 5 V 22 I_c mΑ

Accuracy - Dynamic performance data

v	Accuracy $3 \otimes 1 = 7 = 35^{\circ}$	$ < \pm 1 $	⁰∕ofI
X	Accuracy ³⁾ @ I_{PN} , $T_A = 25^{\circ}C$	≤±1	% of ${\sf I}_{_{\sf PN}}$
\mathcal{E}_{L}	Linearity error 0 3 x I _{PN}	≤ ± 0.5	% of $I_{_{\rm PN}}$
TCV	Temperature coefficient of $V_{OE} \otimes I_{P} = 0$	≤±0.3	mV/K
	F Temperature coefficient of V REF	≤ ± 0.01	%/K
TCV _{OUT} /V _{RE}	Temperature coefficient of $\mathbf{V}_{OUT} / \mathbf{V}_{REF} \textcircled{O} \mathbf{I}_{P} = 0$	≤ ± 0.2	mV/K
TCV _{OU}	$_{\tau}$ Temperature coefficient of V _{OUT}	≤±0.05% c	of reading/K
V _{OM}	Magnetic offset voltage @ $I_P = 0$,		
	after an overload of 3 x $I_{PN DC}$ HAIS 50-(T)P	< ± 0.5	% of $I_{_{\rm PN}}$
	HAIS 100-(T)P400-F	P <±0.4	% of $I_{_{\rm PN}}$
t _{ra}	Reaction time @ 10 % of I _{PN}	< 3	μs
t	Response time to 90 % of I _{PN} step	< 5	μs
di/dt	di/dt accurately followed	> 100	A/µs
V _{no}	Output voltage noise (DC10 kHz)	< 15	mVpp
-	(DC 1 MHz)	< 40	mVpp
BW	Frequency bandwidth (- 3 dB) ⁴⁾	DC 50	kHz

Notes : ¹⁾-TP version is equipped with a primary bus bar.

²⁾ It is possible to overdrive \mathbf{V}_{REF} with an external reference voltage between 2 - 2.8 V providing its ability to sink or source approximately 2.5 mA.

³⁾Excluding offset and hysteresis.

⁴⁾Small signal only to avoid excessive heatings of the magnetic core.

I_{PN} = 50 .. 400 A



Features

- Hall effect measuring principle
- Galvanic isolation between
 primary and secondary circuit
- Isolation test voltage 2500V
- Low power consumption
- Single power supply +5V
- Fixed offset & gain
- Bus bar version available for 50A and 100A ratings.
- Isolated plastic case recognized according to UL94-V0.

Advantages

- Small size and space saving
- Only one design for wide current ratings range
- High immunity to external interference.
- V_{REF}. IN/OUT

Applications

- AC variable speed drives
- Static converters for DC motor drives
- Battery supplied applications
- Uninterruptible Power Supplies
 (UPS)
- Switched Mode Power Supplies (SMPS)
- Power supplies for welding applications.

Application domain

Industrial.



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General data						
T _A T _S M	Ambient operating temperature Ambient storage temperature Mass (in brackets : TP version) Standards		- 40 + 85 - 40 + 85 20 (30) EN 50178: 19	°C °C g 997		
Isolation characteristics						
V _b	Rated isolation voltage rms with IEC 61010-1 standards and fo - Single insulation - Over voltage category III - Pollution degree 2 - Heterogeneous field	llowing conditions	300	V rms		
V _b	Rated isolation voltage rms with EN 50178 standards and follow - Reinforced insulation - Over voltage category III - Pollution degree 2 - Heterogeneous field	wing conditions	600	V rms		
V _d V _e	Rms voltage for AC isolation test, 5	Rms voltage for AC isolation test, 50 Hz, 1 min Partial discharge extinction voltage rms @ 10pC		kV		
c		HAIS 50400-P	> 1	kV		
<u>^</u>		HAIS 50100-TP	> 1.4	kV		
Ŷ	Impulse withstand voltage 1.2/50 µs		8	kV		
dCp dCl	Creepage distance Clearance distance		> 8	mm		
CTI	Comparative tracking index (Group		> 8 > 600	mm		
Cofe	If insulated cable is used for the pri voltage category could be improved Cable insulation (primary) HAR 03 HAR 05 HAR 07	mary circuit, the				

Safety

This transducer must be used in electric/electronic equipment with respect to applicable standards and safety requirements in accordance with the manufacturer's operating instructions.

Caution, risk of electrical shock

When operating the transducer, certain parts of the module can carry hazardous voltage (eg. primary busbar, power supply).

Ignoring this warning can lead to injury and/or cause serious damage.

This transducer is a built-in device, whose conducting parts must be inaccessible after installation.

A protective housing or additional shield could be used. Main supply must be able to be disconnected.

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Dimensions HAIS 50..400-P and HAIS 50..100-TP (in mm. 1 mm = 0.0394 inch)

